

isc N-Channel MOSFET Transistor

FCPF2250N80Z

• FEATURES

- With TO-220F packaging
- High speed switching
- Low gate input resistance
- Standard level gate drive
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATIONS

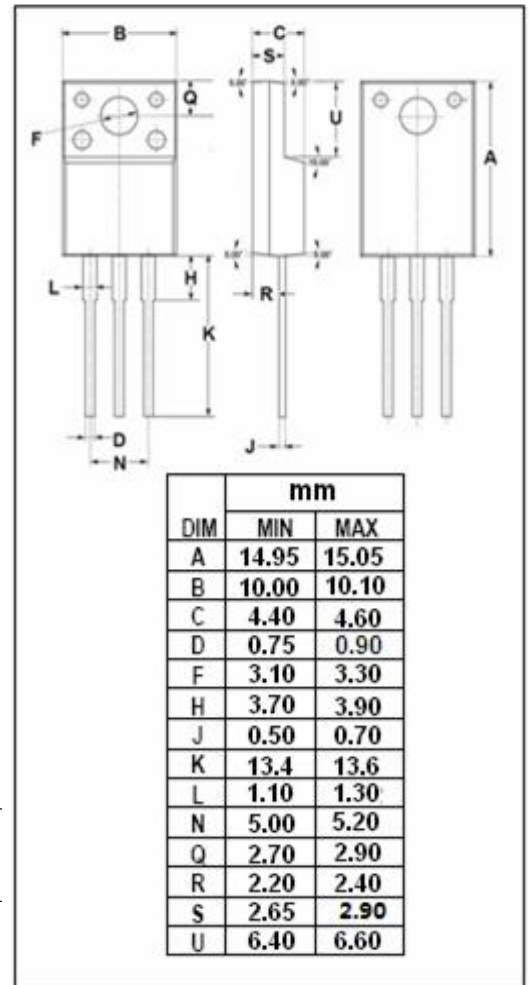
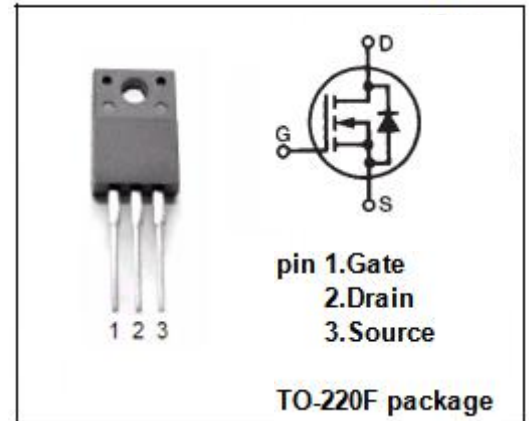
- Power supply
- Switching applications

• ABSOLUTE MAXIMUM RATINGS($T_a=25^{\circ}\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DS}	Drain-Source Voltage	800	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous; @ $T_c=25^{\circ}\text{C}$	3.5	A
I_{DM}	Drain Current-Single Pulsed	6.5	A
P_D	Total Dissipation	21.9	W
T_j	Operating Junction Temperature	-55~150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-55~150	$^{\circ}\text{C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	5.7	$^{\circ}\text{C/W}$



isc N-Channel MOSFET Transistor**FCPF2250N80Z****ELECTRICAL CHARACTERISTICS****T_c=25°C unless otherwise specified**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	800			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.26mA	2.5		4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 1.3A			2.25	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0V			± 10	uA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 800V; V _{GS} = 0V V _{DS} = 640V; V _{GS} = 0V; T _J =125°C			25 250	μ A
V _{SDF}	Diode forward voltage	I _{SD} =10A, V _{GS} = 0 V			1.2	V

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